## NSN 5962-01-232-3021

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View Online at https	://aerobasegroup.com/nsn/5962-01-232-3021
Body Length:	
0.886 inches	
Body Width:	
0.310 inches	
Body Height:	
0.140 inches	
Operating Tempur	ature Range:
-55.0 to 125.0 degre	es celsius
Storage Tempurate	ure Range:
-65.0 to 150.0 degre	es celsius
Features Provided	
Monolithic and prog	rammable and 3-state output and burn in
Inclosure Material:	
Ceramic and glass	
Inclosure Configur	ation:
Dual-in-line	
Output Logic Form	n.
Transistor-transistor	logic
Input Circuit Patter	n:
10 input	
Terminal Surface 1	reatment:
Solder	
Voltage Rating And	d Type Per Characteristic:
7.0 volts power sou	rce
Time Rating Per C	nacteristic:
70.00 nanoseconds	propagation delay time, low to high level output and 70.00 nanoseconds propagation delay time, high to low level
output	
Memory Device Ty	pe:
Rom	
Test Data Docume	nt:
96906-mil-std-883 s	tandard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And	I Quantity:
16 printed circuit	
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
Yes - demil/mli	
Fiig:	
A458a0	